

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	30705 7	(liquid adj crystal) or lcd	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 15:08
2	BRS	L2	2407	1 and light adj leak\$	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 09:07
3	BRS	L3	107	2 and cross adj talk	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 08:37
4	BRS	L4	1	1 and (light adj leak\$ adj data)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 08:45

	Type	L #	Hits	Search Text	DBs	Time Stamp
5	BRS	L5	502	2 and black adj matrix	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 14:17
6	BRS	L6	8	5 and semiconductor adj pattern	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 09:15
7	BRS	L7	2	6380559.pn.	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB.	2002/07/2 2 09:07
8	BRS	L8	245	5 and semiconductor	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 10:10

	Type	L #	Hits	Search Text	DBs	Time Stamp
9	BRS	L9	184	5 and semiconductor adj (pattern or layer)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 10:13
10	BRS	L10	63	9 and data adj line	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 09:17
11	BRS	L11	1510	2 and (black or light adj (block\$ or shield\$ or intercept\$))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 10:09
12	BRS	L12	717	2 and light adj (blocking or shielding or interception)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 12:00

	Type	L #	Hits	Search Text	DBs	Time Stamp
13	BRS	L13	303	12 and semiconductor	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 11:56
14	BRS	L14	191	12 and semiconductor adj (pattern or layer)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 11:55
15	BRS	L15	51	14 and data adj line	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 10:14
16	BRS	L16	233	12 and amorphous adj silicon	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 11:56

	Type	L #	Hits	Search Text	DBs	Time Stamp
17	BRS	L17	351	12 and ((amorphous adj silicon) or semiconductor)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/07/2 2 12:01
18	BRS	L18	1429	2 and (black or light adj (blocking or shielding or interception))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/07/2 2 13:26
19	BRS	L19	589	18 and ((amorphous adj silicon) or semiconductor)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/07/2 2 12:01
20	BRS	L20	117	19 and overlap\$ near (common or pixel)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM_ TDB	2002/07/2 2 12:03

	Type	L #	Hits	Search Text	DBs	Time Stamp
21	BRS	L21	141	19 and overlap\$ near (data or common or pixel)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 13:28
22	BRS	L22	1167	2 and (black or light adj (blocking or shielding or interception) with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 15:11
23	BRS	L23	1167	2 and (black or light adj (blocking or shielding or interception) with (amorphous adj silicon))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 13:28
24	BRS	L24	146	23 and overlap\$ near (data or common or pixel)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 13:29

	Type	L #	Hits	Search Text	DBs	Time Stamp
25	BRS	L25	0	2 and ((black adj matrix) near (amorphous or semiconductor))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 14:20
26	BRS	L26	0	2 and ((light adj interception) near (amorphous or semiconductor))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 14:20
27	BRS	L27	1	2 and ((light adj interception) with (amorphous or semiconductor))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 14:20
28	BRS	L28	36	2 and ((black adj matrix) with (amorphous or semiconductor))	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 14:23

	Type	L #	Hits	Search Text	DBs	Time Stamp
29	BRS	L29	640	2 and (black adj matrix with amorphous or semiconductor)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 14:23
30	BRS	L30	39931	thin adj film adj transistor or tft	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 15:10
31	BRS	L31	898	349/110	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 15:10
32	BRS	L32	617	31 and (black or light adj (blocking or shielding or interception) with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2002/07/2 2 15:12

	Type	L #	Hits	Search Text	DBs	Time Stamp
33	BRS	L33	9	31 and (light adj shielding with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2002/07/2 2 15:33
34	BRS	L34	4	31 and (light adj blocking with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2002/07/2 2 15:28
35	BRS	L35	0	31 and (light adj interception with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2002/07/2 2 15:29
36	BRS	L36	6	31 and (black adj matrix with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2002/07/2 2 15:29

	Type	L #	Hits	Search Text	DBs	Time Stamp
37	BRS	L37	70	30 and (light adj shielding with amorphous adj silicon)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2002/07/2 2 15:34